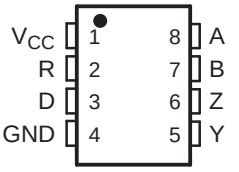
SN65LVDS179-EP, SN65LVDS180-EP SN65LVDS050-EP, SN65LVDS051-EP HIGH-SPEED DIFFERENTIAL LINE DRIVERS AND RECEIVERS

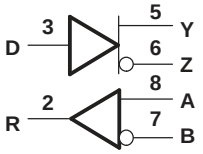
SGLS203B – SEPTEMBER 2003 – REVISED JANUARY 2007

FEATURES

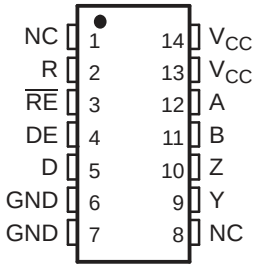
- **Controlled Baseline**
  - **One Assembly/Test Site, One Fabrication Site**
- **Enhanced Diminishing Manufacturing Sources (DMS) Support**
- **Enhanced Product-Change Notification**
- **Qualification Pedigree** (1)
- **Meet or Exceed the Requirements of ANSI TIA/EIA-644-1995 Standard**
- **Signaling Rates up to 400 Mbps**
- **Bus-Terminal ESD Exceeds 12 kV**
- **Operates From a Single 3.3-V Supply**
- **Low-Voltage Differential Signaling With Typical Output Voltages of 350 mV and a 100-Ω Load**
- **Propagation Delay Times**
  - **Driver: 1.7 ns Typ**
  - **Receiver: 3.7 ns Typ**
- **Power Dissipation at 200 MHz**
  - **Driver: 25 mW Typical**
  - **Receiver: 60 mW Typical**
- **LVTTL Input Levels Are 5-V Tolerant**
- **Receiver Maintains High Input Impedance With V_{CC} < 1.5 V**
- **Receiver Has Open-Circuit Fail Safe**

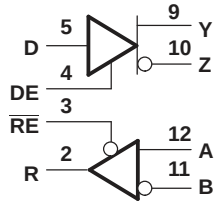
SN65LVDS179
D OR DGK PACKAGE
(TOP VIEW)



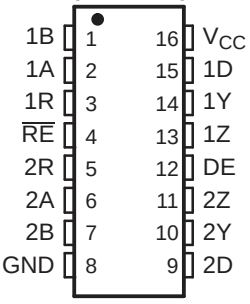


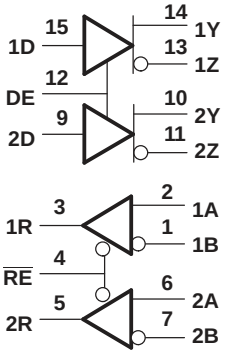
SN65LVDS180
D OR PW PACKAGE
(TOP VIEW)



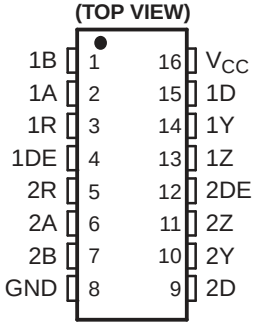


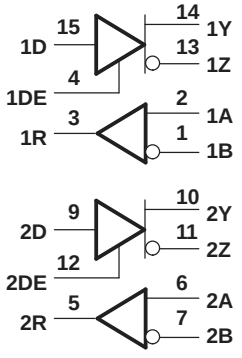
SN65LVDS050
D OR PW PACKAGE
(TOP VIEW)





SN65LVDS051
D OR PW PACKAGE
(TOP VIEW)





(1) Component qualification in accordance with JEDEC and industry standards to ensure reliable operation over an extended temperature range. This includes, but is not limited to, Highly Accelerated Stress Test (HAST) or biased 85/85, temperature cycle, autoclave or unbiased HAST, electromigration, bond intermetallic life, and mold compound life. Such qualification testing should not be viewed as justifying use of this component beyond specified performance and environmental limits.

DESCRIPTION/ORDERING INFORMATION

The SN65LVDS179, SN65LVDS180, SN65LVDS050, and SN65LVDS051 are differential line drivers and receivers that use low-voltage differential signaling (LVDS) to achieve signaling rates as high as 400 Mbps. The TIA/EIA-644 standard compliant electrical interface provides a minimum differential output voltage magnitude of 247 mV into a 100-Ω load, and receipt of 100-mV signals with up to 1 V of ground potential difference between a transmitter and receiver.

DESCRIPTION/ORDERING INFORMATION (CONTINUED)

The intended application of this device and signaling technique is for point-to-point baseband data transmission over controlled impedance media of approximately 100-Ω characteristic impedance. The transmission media may be printed circuit board traces, backplanes, or cables. (Note: The ultimate rate and distance of data transfer is dependent upon the attenuation characteristics of the media, the noise coupling to the environment, and other application specific characteristics.)

The devices offer various driver, receiver, and enabling combinations in industry standard footprints. Since these devices are intended for use in simplex or distributed simplex bus structures, the driver enable function does not put the differential outputs into a high-impedance state, but rather disconnects the input and reduces the quiescent power used by the device. (For these functions with a high-impedance driver output, see the SN65LVDM series of devices.) All devices are characterized for operation from –55°C to 125°C.

AVAILABLE OPTIONS(1)

T_A	PACKAGE		
	SMALL OUTLINE (D)	SMALL OUTLINE (DGK)	SMALL OUTLINE (PW)
-55°C TO 125°C	SN65LVDS050MDREP(2)		SN65LVDS050MPWREP(2)
	SN65LVDS051MDREP(2)		SN65LVDS051MPWREP(2)
	SN65LVDS179MDREP(2)	SN65LVDS179MDGKREP	
	SN65LVDS180MDREP(2)		SN65LVDS180MPWREP(2)

(1) For the most current packaging and odering infomation, see the Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.
(2) Product Preview

FUNCTION TABLES

SN65LVDS179 Receiver(1)

INPUTS	OUTPUT
$V_{ID} = V_A - V_B$	R
$V_{ID} \geq 100$ mV	H
-100 mV $< V_{ID} < 100$ mV	?
$V_{ID} \geq 100$ mV	L
Open	H

(1) H = high level, L = low level, ? = indeterminate

SN65LVDS179 Driver(1)

INPUT	OUTPUTS	
D	Y	Z
L	L	H
H	H	L
Open	L	H

(1) H = high level, L = low level

SN65LVDS180, SN65LVDS050, and SN65LVDS051 Receiver(1)

INPUTS		OUTPUT
$V_{ID} = V_A - V_B$	$\overline{RE}$	R
$V_{ID} \geq 100$ mV	L	H
-100 mV $< V_{ID} < 100$ mV	L	?
$V_{ID} \leq -100$ mV	L	L
Open	L	H
X	H	Z

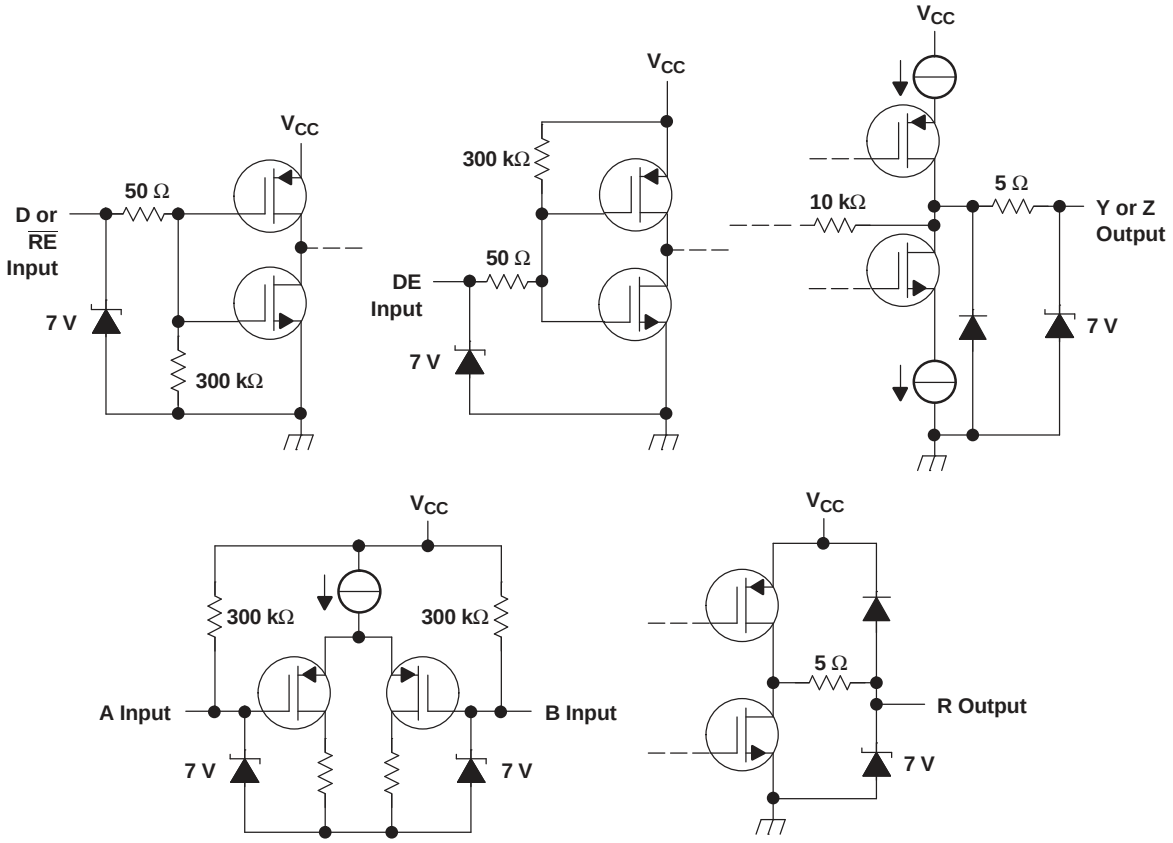
(1) H = high level, L = low level, Z = high impedance, X = don't care

SN65LVDS180, SN65LVDS050, and SN65LVDS051 Driver(1)

INPUTS		OUTPUTS	
D	DE	Y	Z
L	H	L	H
H	H	H	L
Open	H	L	H
X	L	OFF	OFF

(1) H = high level, L = low level, OFF = No Output, X = don't care

EQUIVALENT INPUT AND OUTPUT SCHEMATIC DIAGRAMS



Absolute Maximum Ratings(1)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_{CC}	Supply voltage range(2)		–0.5	4	V
	Voltage range	D, R, DE, and $\overline{RE}$	–0.5	6	V
		Y, Z, A, and B	–0.5	4	
	Electrostatic discharge	Y, Z, A, B, and GND(3)	Class 3, A: 12 kV, B: 600 V		
		All	Class 3, A: 7 kV, B: 500 V		
	Continuous power dissipation		See Dissipation Rating Table		
	Storage temperature range		– 65	150	°C
	Lead temperature 1,6 mm (1/16 in) from case for 10 s			250	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) All voltage values, except differential I/O bus voltages are with respect to network ground terminal.
(3) Tested in accordance with MIL-STD-883C Method 3015.7

Dissipation Ratings Table

PACKAGE	$T_A \le 25°C$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25°C$(1)	$T_A = 85°C$ POWER RATING	$T_A = 125°C$ POWER RATING
DGK	424 mW	3.4 mW/°C	220 mW	84mW
PW(14)	736mw	5.9 mW/Â°C	383 mW	146mW
PW(16)	839mw	6.7 mW/Â°C	437 mW	169mW
D(8)	635mw	5.1 mW/Â°C	330 mW	125mW
D(14)	987mw	7.9 mW/Â°C	513 mW	197mW
D(16)	1110mw	8.9 mW/Â°C	577 mW	220mW

(1) This is the inverse of the junction-to-ambient thermal resistance when board mounted and with no air flow.

Recommended Operating Conditions

		MIN	NOM	MAX	UNIT
V_{CC}	Supply voltage	3	3.3	3.6	V
V_{IH}	High-level input voltage	2			V
V_{IL}	Low-level input voltage			0.8	V
$\lvert V_{ID}\rvert$	Magnitude of differential input voltage	0.1		0.6	V
$\lvert V_{OD(dis)}\rvert$	Magnitude of differential output voltage with disabled driver			520	mV
V_{OY} or V_{OZ}	Driver output voltage	0		2.4	V
V_{IC}	Common-mode input voltage (see Figure 5)	$\frac{\lvert V_{ID}\rvert}{2}$		$2.4 - \frac{\lvert V_{ID}\rvert}{2}$	V
				$V_{CC} - 0.8$	
T_A	Operating free-air temperature(1)	–55		125	°C

(1) Long term high-temperature storage and/or extended use at maximum recommended operating conditions may result in a reduction of overall device life. See http://www.ti.com/ep_quality for additional information on enhanced plastic packaging

Device Electrical Characteristics

over recommended operating conditions (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP(1)	MAX	UNIT
I_{CC} Supply current	SN65LVDS179	No receiver load, Driver R_L = 100 Ω		9	12	mA
	SN65LVDS180	Driver and receiver enabled, No receiver load, Driver R_L = 100 Ω		9	12	mA
		Driver enabled, Receiver disabled, R_L = 100 Ω		5	7	
		Driver disabled, Receiver enabled, No load		1.5	2	
		Disabled		0.5	1	
	SN65LVDS050	Drivers and receivers enabled, No receiver loads, Driver R_L = 100 Ω		12	20	mA
		Drivers enabled, Receivers disabled, R_L = 100 Ω		10	16	
		Drivers disabled, Receivers enabled, No loads		3	6	
		Disabled		0.5	1	
	SN65LVDS051	Drivers enabled, No receiver loads, Driver R_L = 100 Ω		12	20	mA
		Drivers disabled, No loads		3	6	

(1) All typical values are at 25°C and with a 3.3-V supply.

Driver Electrical Characteristics

over recommended operating conditions (unless otherwise noted)

PARAMETER			TEST CONDITIONS	MIN	TYP	MAX	UNIT
$\|V_{OD}\|$	Differential output voltage magnitude		R_L = 100 Ω, See Figure 1 and Figure 2	247	340	454	mV
$\Delta\|V_{OD}\|$	Change in differential output voltage magnitude between logic states			–50		50	
$V_{OC(SS)}$	Steady-state common-mode output voltage		See Figure 3	1.125	1.2	1.375	V
$\Delta V_{OC(SS)}$	Change in steady-state common-mode output voltage between logic states			–50		50	mV
$V_{OC(PP)}$	Peak-to-peak common-mode output voltage				50	150	mV
I_{IH}	High-level input current	DE	V_{IH} = 5 V		–0.5	–20	µA
		D			2	20	
I_{IL}	Low-level input current	DE	V_{IL} = 0.8 V		–0.5	–10	µA
		D			2	10	
I_{OS}	Short-circuit output current		V_{OY} or V_{OZ} = 0 V		3	10	mA
			V_{OD} = 0 V		3	10	
$I_{O(OFF)}$	Off-state output current		DE = 0 V, V_{OY} = V_{OZ} = 0 V	–1		1	µA
			DE = V_{CC}, V_{OY} = V_{OZ} = 0 V, V_{CC} < 1.5 V				
C_{IN}	Input capacitance				3		pF

Receiver Electrical Characteristics

over recommended operating conditions (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{IT+}	Positive-going differential input voltage threshold	See Figure 5 and Table 1			100	mV
V_{IT-}	Negative-going differential input voltage threshold		–100			
V_{OH}	High-level output voltage	I_{OH} = –8 mA	2.4			V
		I_{OH} = –4 mA	2.8			
V_{OL}	Low-level output voltage	I_{OL} = 8 mA			0.4	V
I_I	Input current (A or B inputs)	V_I = 0	–2	–11	–20	µA
		V_I = 2.4 V	–1.2	–3		
$I_{I(OFF)}$	Power-off input current (A or B inputs)	V_{CC} = 0 V			±20	µA
I_{IH}	High-level input current (enables)	V_{IH} = 5 V			±10	µA
I_{IL}	Low-level input current (enables)	V_{IL} = 0.8 V			±10	µA
I_{OZ}	High-impedance output current	V_O = 0 or 5 V			±10	µA
C_I	Input capacitance			5		pF

Driver Switching Characteristics

over recommended operating conditions (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP(1)	MAX	UNIT
t_{PLH}	Propagation delay time, low- to high-level output	R_L = 100 Ω, C_L = 10 pF, See Figure 2		1.7	4.5	ns
t_{PHL}	Propagation delay time, high- to low-level output			1.7	4.5	ns
t_r	Differential output signal rise time			0.8	1.2	ns
t_f	Differential output signal fall time			0.8	1.2	ns
$t_{sk(p)}$	Pulse skew ($\lvert t_{PHL} - t_{PLH} \rvert$)(2)			300		ps
$t_{sk(o)}$	Channel-to-channel output skew(3)			150		ps
t_{en}	Enable time	See Figure 4		4.3	10	ns
t_{dis}	Disable time			3.1	10	ns

(1) All typical values are at 25°C and with a 3.3-V supply.
(2) $t_{sk(p)}$ is the magnitude of the time difference between the high-to-low and low-to-high propagation delay times at an output.
(3) $t_{sk(o)}$ is the magnitude of the time difference between the outputs of a single device with all of their inputs connected together.

Receiver Switching Characteristics

over recommended operating conditions (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP(1)	MAX	UNIT
t_{PLH}	Propagation delay time, low- to high-level output	C_L = 10 pF, See Figure 6		3.7	4.5	ns
t_{PHL}	Propagation delay time, high- to low-level output			3.7	4.5	ns
$t_{sk(p)}$	Pulse skew ($\lvert t_{PHL} - t_{PLH} \rvert$)(2)			0.3		ns
t_r	Output signal rise time			0.7	1.5	ns
t_f	Output signal fall time			0.9	1.5	ns
t_{PZH}	Propagation delay time, high-impedance to high-level output	See Figure 7		2.5		ns
t_{PZL}	Propagation delay time, high-impedance to low-level output			2.5		ns
t_{PHZ}	Propagation delay time, high-level to high-impedance output			7		ns
t_{PLZ}	Propagation delay time, low-level to high-impedance output			4		ns

(1) All typical values are at 25°C and with a 3.3-V supply.
(2) $t_{sk(p)}$ is the magnitude of the time difference between the high-to-low and low-to-high propagation delay times at an output.

PARAMETER MEASUREMENT INFORMATION

Driver

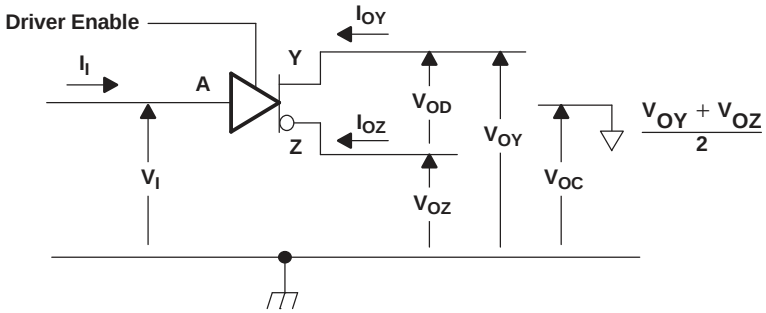
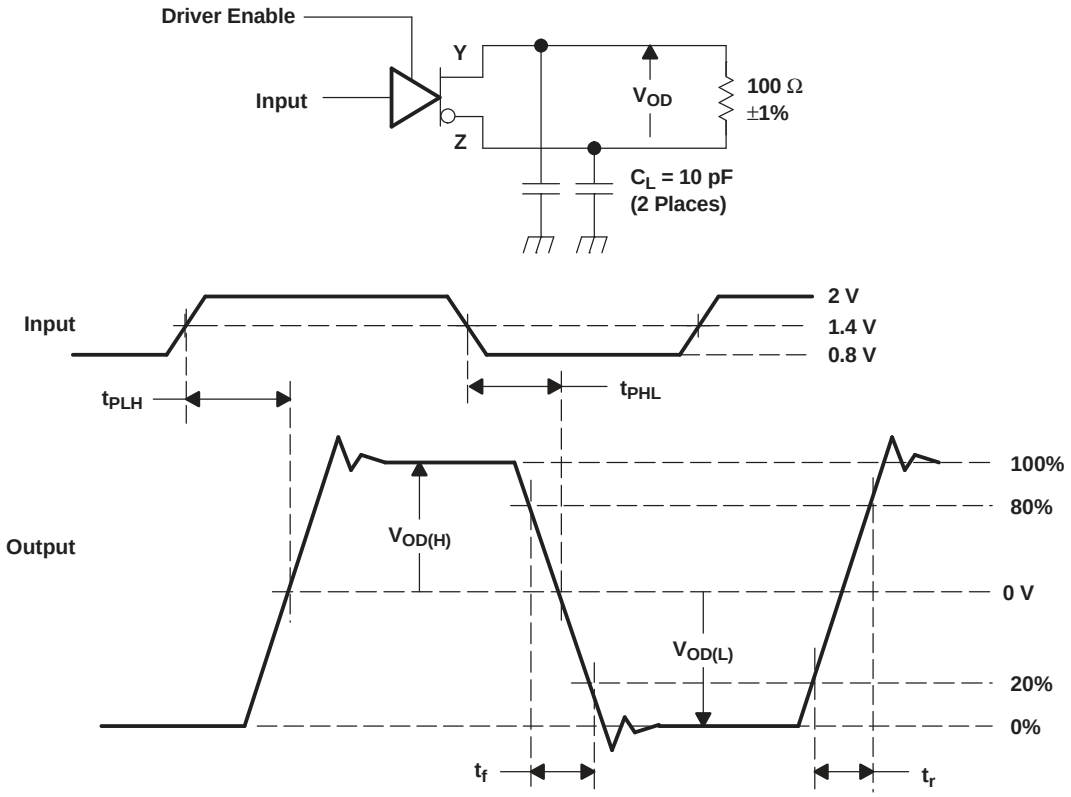


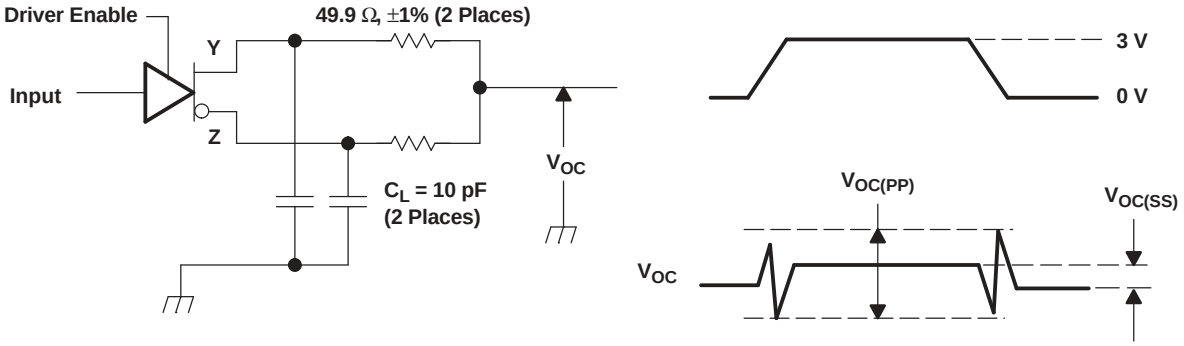
Figure 1. Driver Voltage and Current Definitions



A. All input pulses are supplied by a generator having the following characteristics: t_r or $t_f \leq 1$ ns, pulse repetition rate (PRR) = 50 Mpps, pulse width = 10 ± 0.2 ns. C_L includes instrumentation and fixture capacitance within 0,06 mm of the D.U.T.

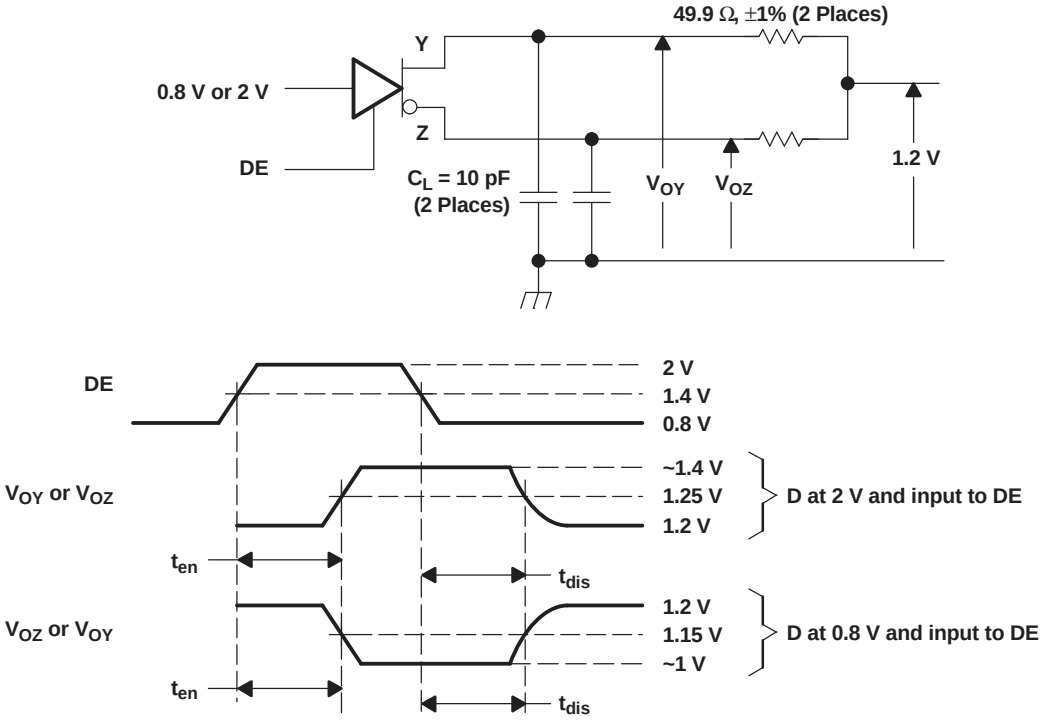
Figure 2. Test Circuit, Timing, and Voltage Definitions for the Differential Output Signal

PARAMETER MEASUREMENT INFORMATION (continued)



A. All input pulses are supplied by a generator having the following characteristics: t_r or $t_f \le 1$ ns, pulse repetition rate (PRR) = 50 Mpps, pulse width = 10 ± 0.2 ns. C_L includes instrumentation and fixture capacitance within 0,06 mm of the D.U.T. The measurement of $V_{OC(PP)}$ is made on test equipment with a –3-dB bandwidth of at least 300 MHz.

Figure 3. Test Circuit and Definitions for the Driver Common-Mode Output Voltage



A. All input pulses are supplied by a generator having the following characteristics: t_r or $t_f \le 1$ ns, pulse repetition rate (PRR) = 0.5 Mpps, pulse width = 500 ± 10 ns. C_L includes instrumentation and fixture capacitance within 0,06 mm of the D.U.T.

Figure 4. Enable and Disable Time Circuit and Definitions

PARAMETER MEASUREMENT INFORMATION (continued)

Receiver

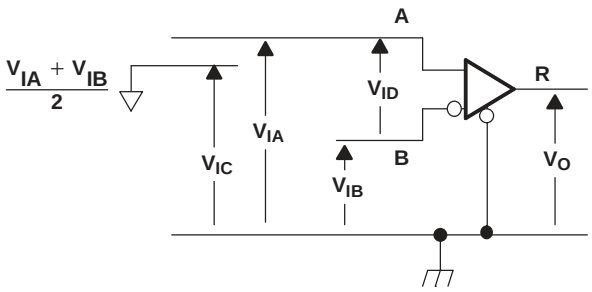
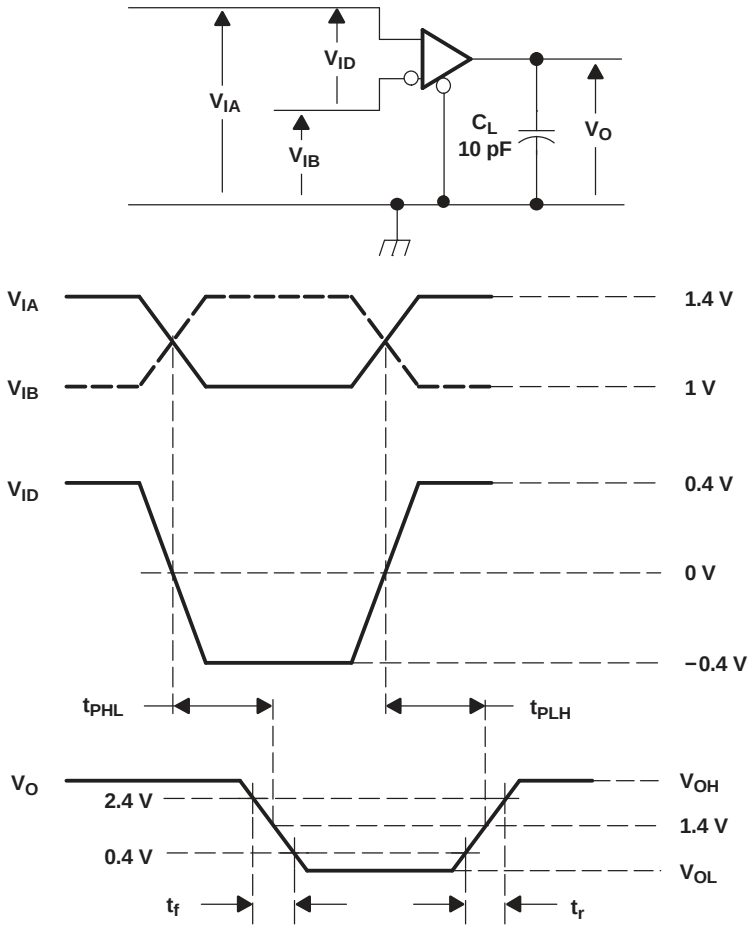


Figure 5. Receiver Voltage Definitions

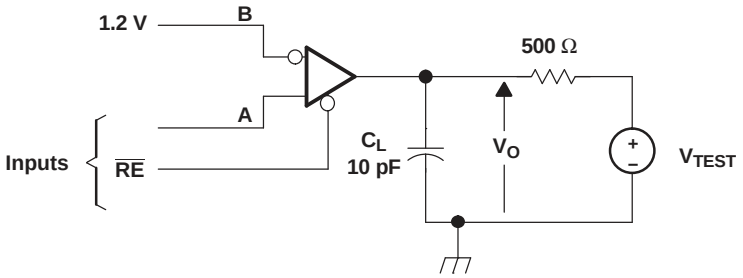
Table 1. Receiver Minimum and Maximum Input Threshold Test Voltages

APPLIED VOLTAGES (V)		RESULTING DIFFERENTIAL INPUT VOLTAGE (mV)	RESULTING COMMON-MODE INPUT VOLTAGE (V)
V_{IA}	V_{IB}	V_{ID}	V_{IC}
1.25	1.15	100	1.2
1.15	1.25	–100	1.2
2.4	2.3	100	2.35
2.3	2.4	–100	2.35
0.1	0	100	0.05
0	0.1	–100	0.05
1.5	0.9	600	1.2
0.9	1.5	–600	1.2
2.4	1.8	600	2.1
1.8	2.4	–600	2.1
0.6	0	600	0.3
0	0.6	–600	0.3



A. All input pulses are supplied by a generator having the following characteristics: t_r or $t_f \leq 1$ ns, pulse repetition rate (PRR) = 50 Mpps, pulse width = 10 ± 0.2 ns. C_L includes instrumentation and fixture capacitance within 0,06 mm of the D.U.T.

Figure 6. Timing Test Circuit and Waveforms



A. All input pulses are supplied by a generator having the following characteristics: t_r or $t_f \leq 1$ ns, pulse repetition rate (PRR) = 0.5 Mpps, pulse width = 500 ± 10 ns. C_L includes instrumentation and fixture capacitance within 0,06 mm of the D.U.T.

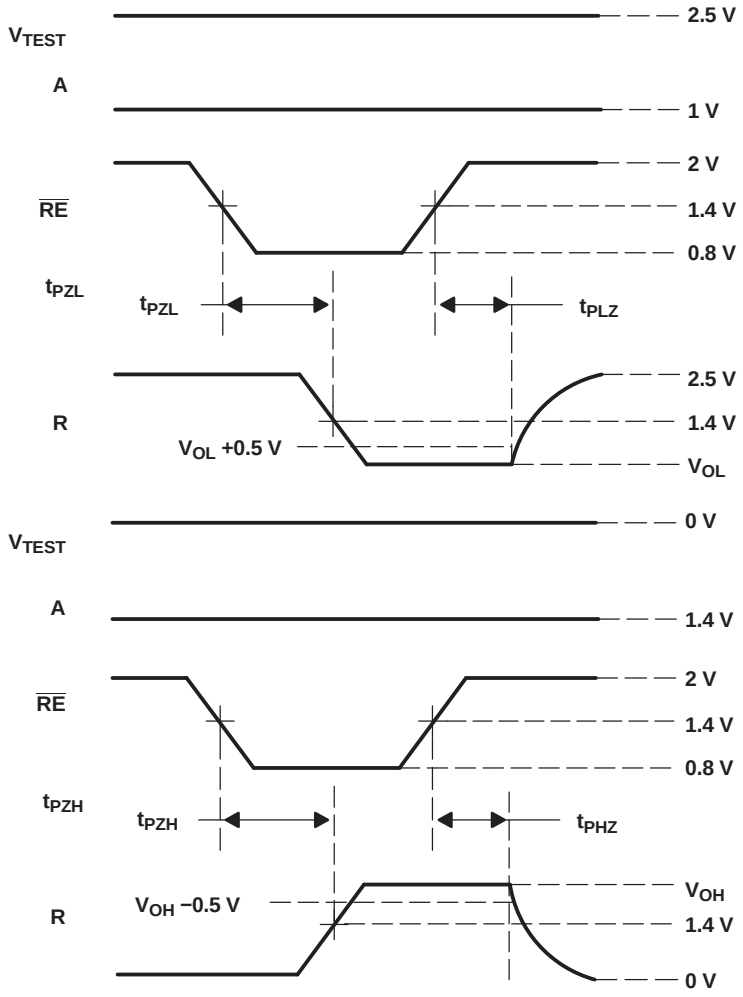


Figure 7. Enable/Disable Time Test Circuit and Waveforms

TYPICAL CHARACTERISTICS

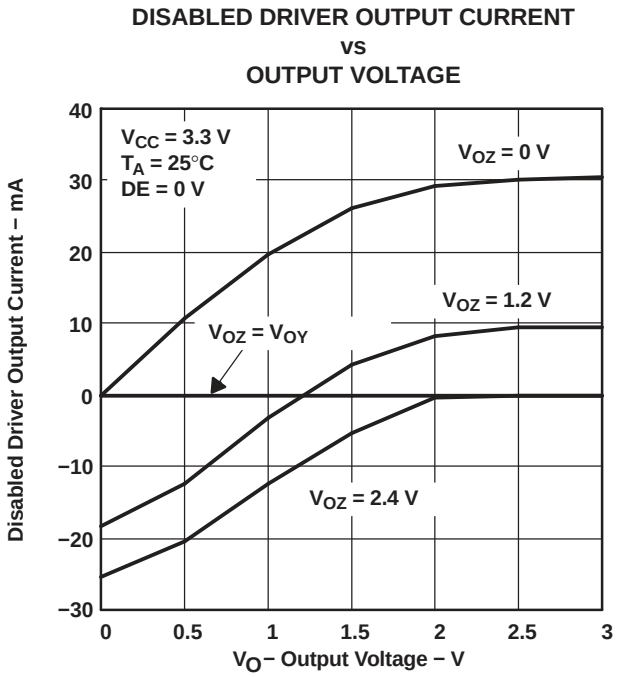


Figure 8.

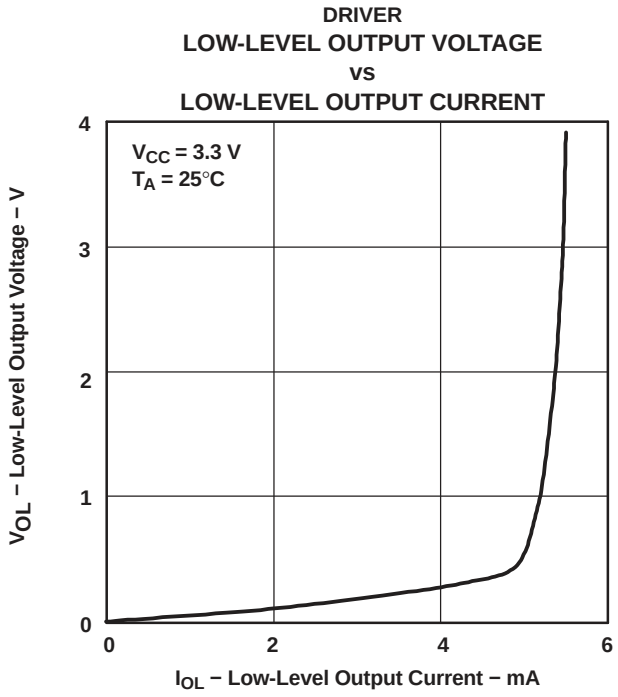


Figure 9.

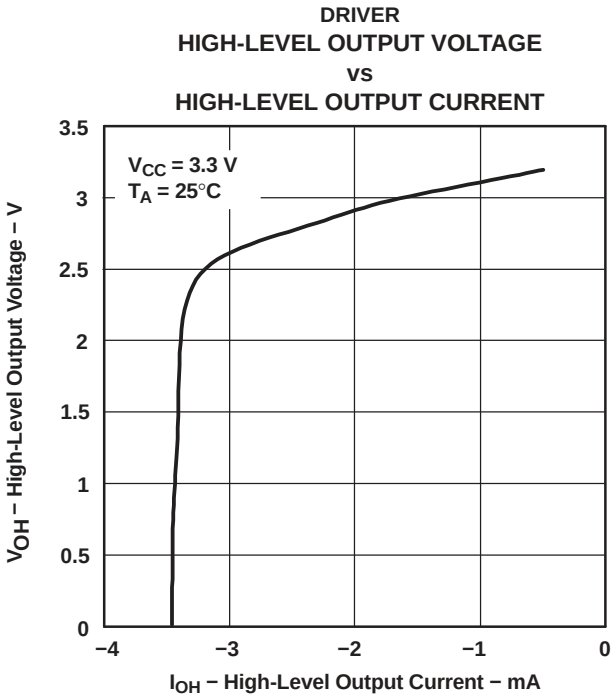


Figure 10.

TYPICAL CHARACTERISTICS (continued)

RECEIVER
LOW-LEVEL OUTPUT VOLTAGE
vs
LOW-LEVEL OUTPUT CURRENT

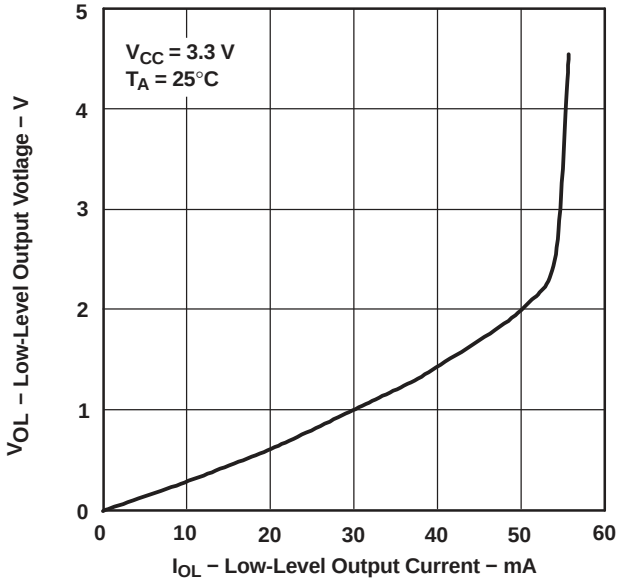


Figure 11.

RECEIVER
HIGH-LEVEL OUTPUT VOLTAGE
vs
HIGH-LEVEL OUTPUT CURRENT

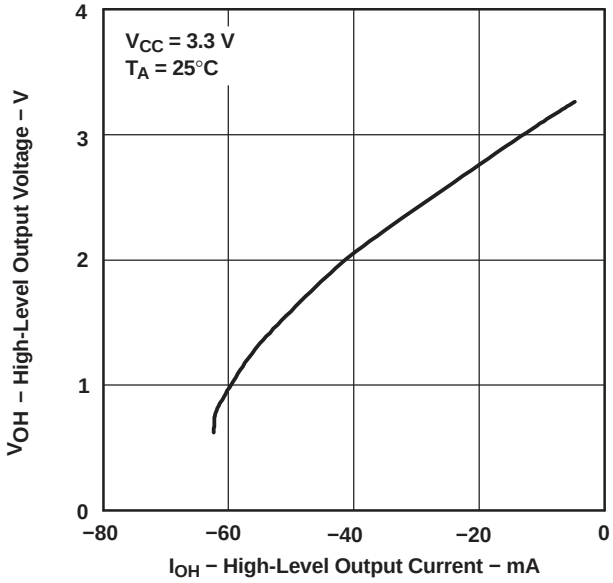


Figure 12.

DRIVER
HIGH- TO LOW-LEVEL PROPAGATION DELAY TIME
vs
FREE-AIR TEMPERATURE

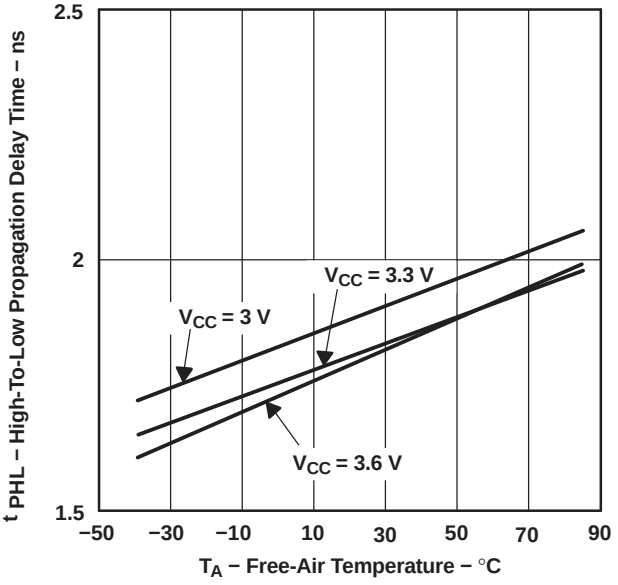


Figure 13.

DRIVER
LOW- TO HIGH-LEVEL PROPAGATION DELAY TIME
vs
FREE-AIR TEMPERATURE

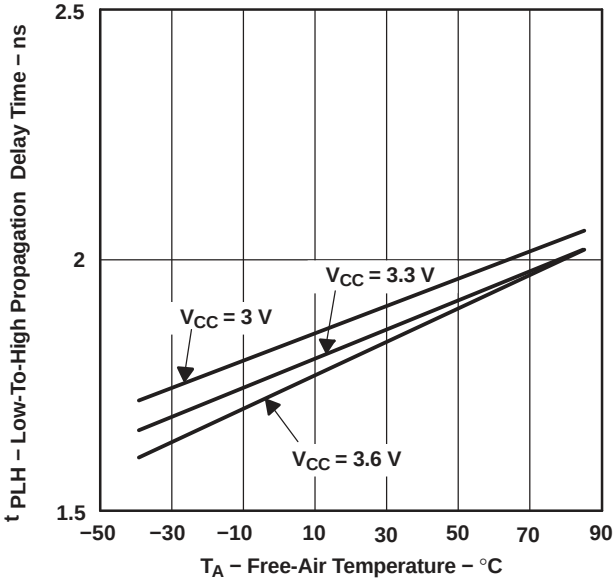


Figure 14.

TYPICAL CHARACTERISTICS (continued)

RECEIVER
HIGH- TO LOW-LEVEL PROPAGATION DELAY TIME
vs
FREE-AIR TEMPERATURE

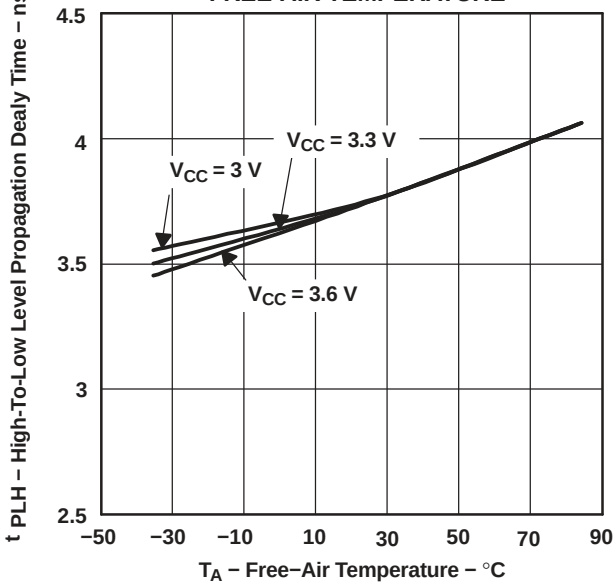


Figure 15.

RECEIVER
LOW- TO HIGH-LEVEL PROPAGATION DELAY TIME
vs
FREE−AIR TEMPERATURE

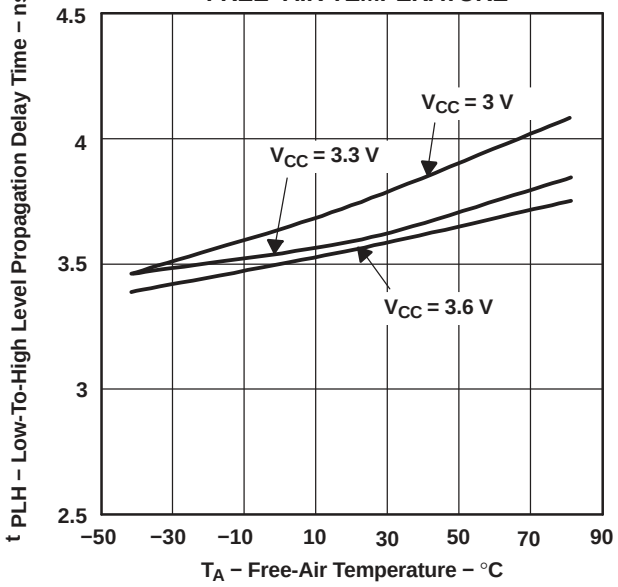


Figure 16.

APPLICATION INFORMATION

The devices are generally used as building blocks for high-speed point-to-point data transmission. Ground differences are less than 1 V with a low common-mode output and balanced interface for very low noise emissions. Devices can interoperate with RS-422, PECL, and IEEE-P1596. Drivers/receivers maintain ECL speeds without the power and dual supply requirements.

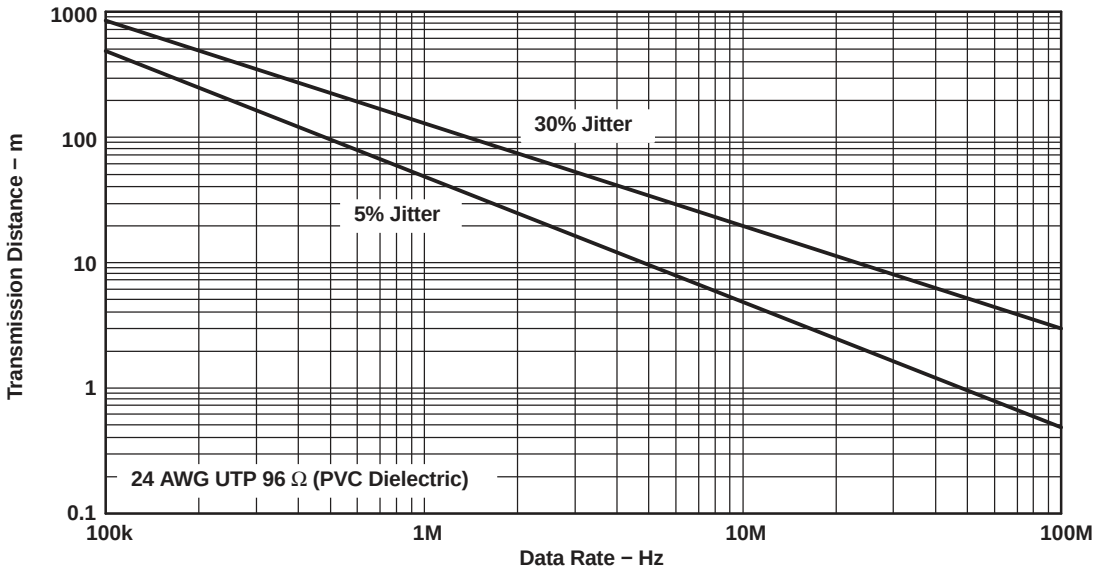


Figure 17. Data Transmission Distance Versus Rate

APPLICATION INFORMATION (continued)

Fail Safe

One of the most common problems with differential signaling applications is how the system responds when no differential voltage is present on the signal pair. The LVDS receiver is like most differential line receivers, in that its output logic state can be indeterminate when the differential input voltage is between –100 mV and 100 mV and within its recommended input common-mode voltage range. However, TI's LVDS receiver is different in how it handles the open-input circuit situation.

Open-circuit means that there is little or no input current to the receiver from the data line itself. This could be when the driver is in a high-impedance state or the cable is disconnected. When this occurs, the LVDS receiver pulls each line of the signal pair to near V_{CC} through 300-kΩ resistors as shown in Figure 18. The fail-safe feature uses an AND gate with input voltage thresholds at about 2.3 V to detect this condition and force the output to a high-level, regardless of the differential input voltage.

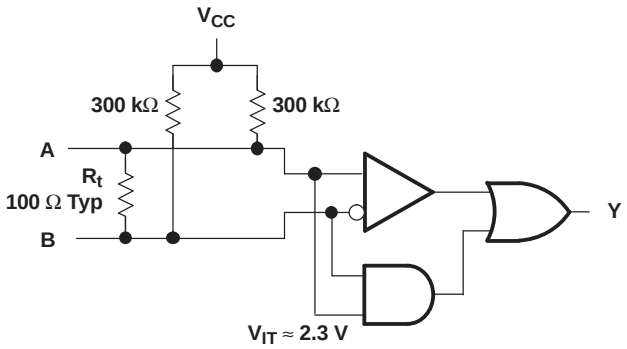


Figure 18. Open-Circuit Fail Safe of the LVDS Receiver

It is only under these conditions that the output of the receiver is valid with less than a 100-mV differential input voltage magnitude. The presence of the termination resistor, R_t, does not affect the fail-safe function as long as it is connected as shown in the figure. Other termination circuits may allow a dc current to ground that could defeat the pullup currents from the receiver and the fail-safe feature.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN65LVDS179MDGKREP	ACTIVE	VSSOP	DGK	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	BZO	Samples
V62/07612-03NE	ACTIVE	VSSOP	DGK	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	BZO	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

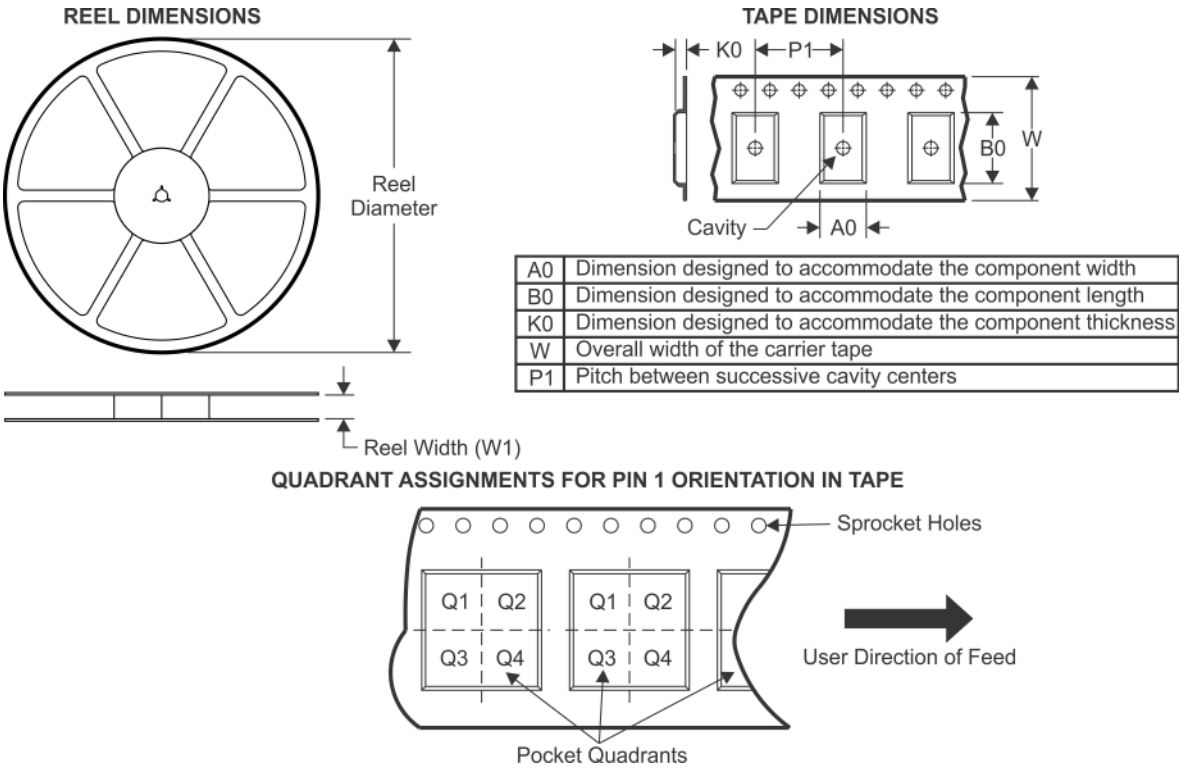
OTHER QUALIFIED VERSIONS OF SN65LVDS179-EP :

- Catalog: SN65LVDS179

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product

TAPE AND REEL INFORMATION

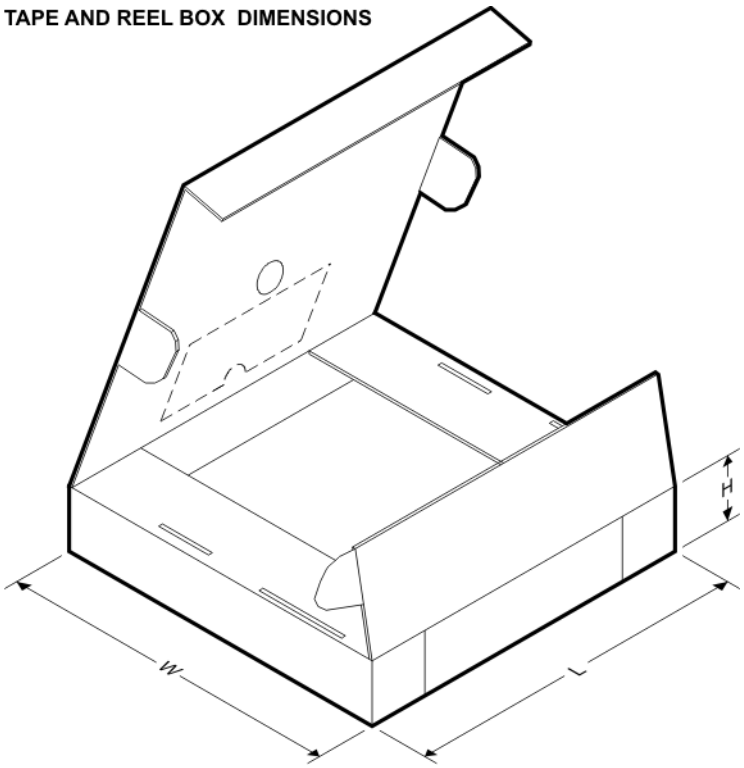


A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN65LVDS179MDGKREP	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1

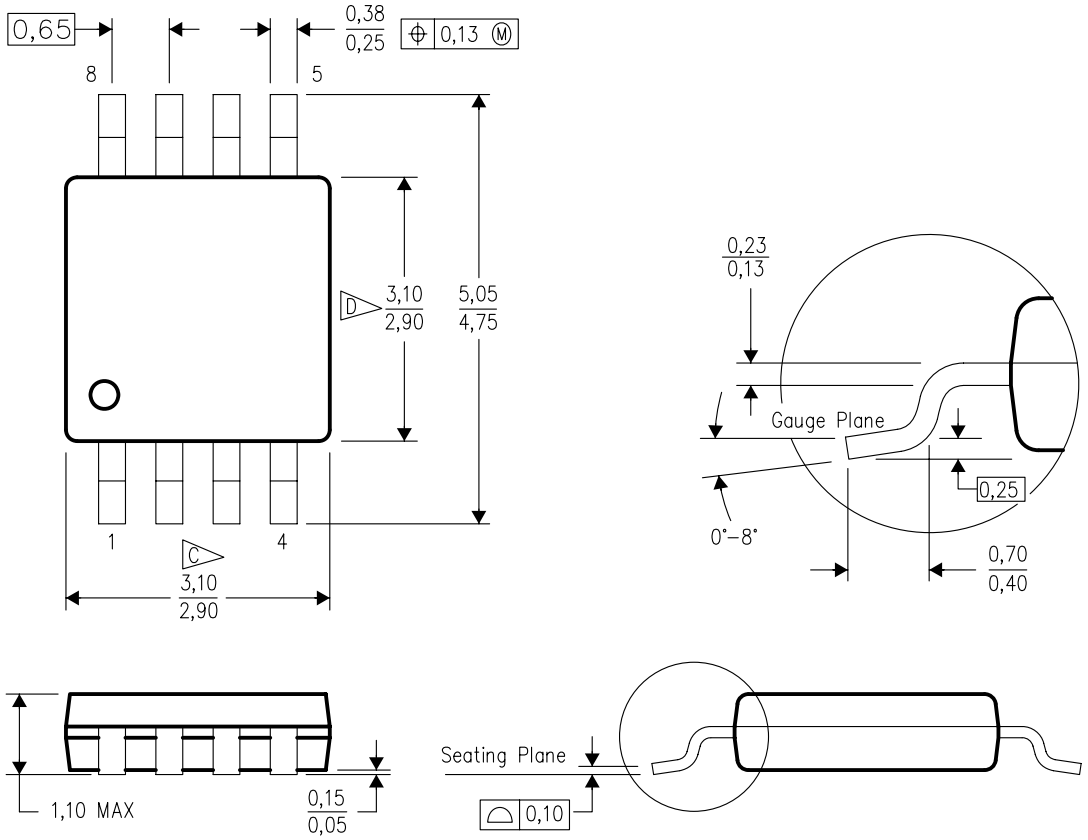
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN65LVDS179MDGKREP	VSSOP	DGK	8	2500	358.0	335.0	35.0

DGK (S–PDSO–G8) PLASTIC SMALL–OUTLINE PACKAGE



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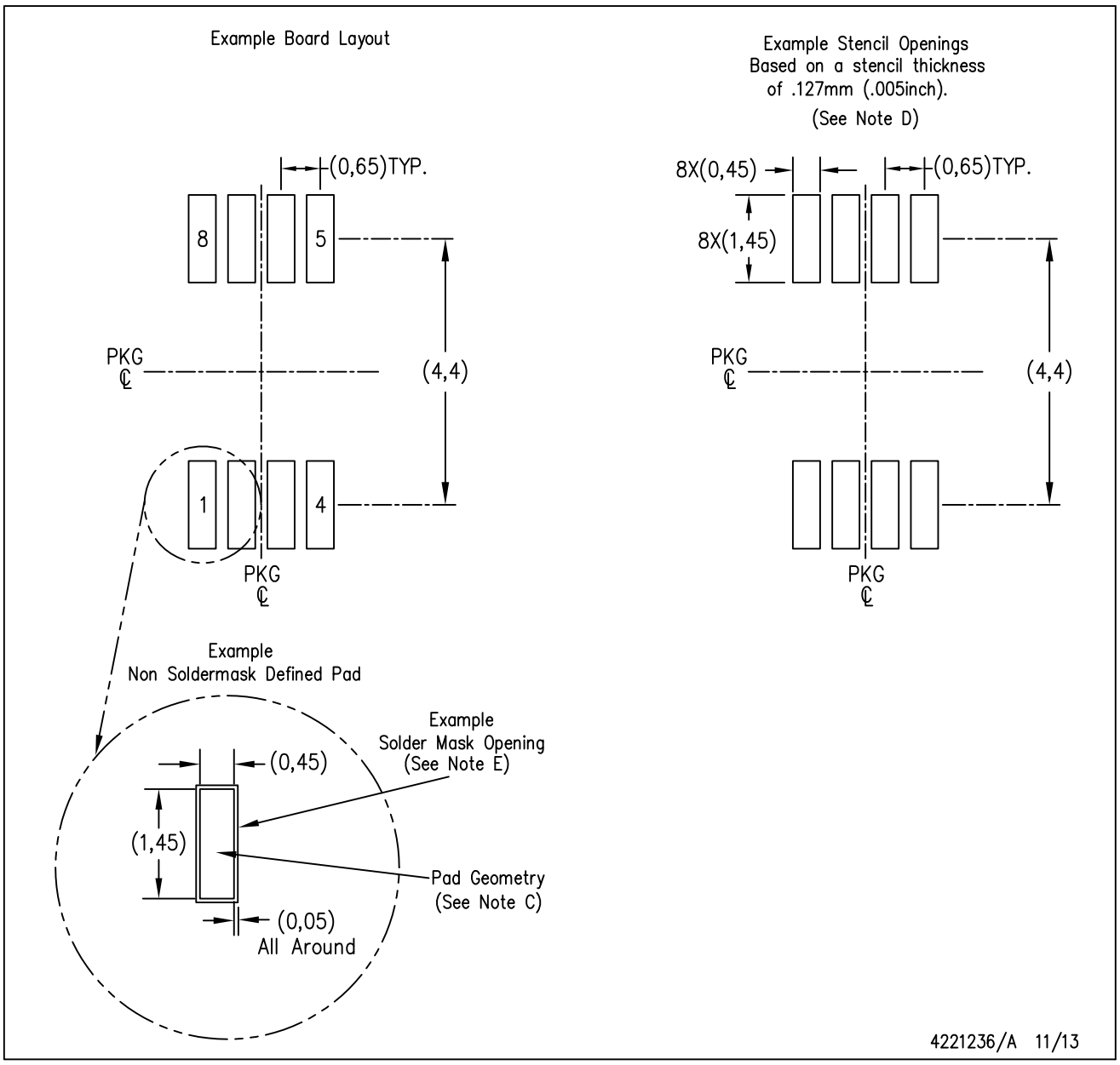
NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per end.
D. Body width does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
E. Falls within JEDEC MO–187 variation AA, except interlead flash.

DGK (S–PDSO–G8) PLASTIC SMALL OUTLINE PACKAGE



NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Publication IPC–7351 is recommended for alternate designs.
D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC–7525 for other stencil recommendations.
E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

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